Designer's™ Data Sheet

SWITCHMODETM

NPN Bipolar Power Transistor For Switching Power Supply Applications

The BUL147/BUL147F have an applications specific state—of—the—art die designed for use in electric fluorescent lamp ballasts to 180 Watts and in Switchmode Power supplies for all types of electronic equipment. These high—voltage/high—speed transistors offer the following:

- Improved Efficiency Due to Low Base Drive Requirements:
 - High and Flat DC Current Gain
 - Fast Switching
 - No Coil Required in Base Circuit for Turn-Off (No Current Tail)
- Parametric Distributions are Tight and Consistent Lot-to-Lot
- Two Package Choices: Standard TO–220 or Isolated TO–220
- BUL147F, Isolated Case 221D, is UL Recognized to 3500 V_{RMS}: File #E69369

MAXIMUM RATINGS

Ratin	Symbol	BUL147	BUL147F	Unit	
Collector–Emitter Sustaining	VCEO	40	Vdc		
Collector–Emitter Breakdow	n Voltage	VCES	700		Vdc
Emitter-Base Voltage		VEBO	9.0		Vdc
Collector Current — Continu — Peak(1	I _C	8.0 16		Adc	
Base Current — Continuous — Peak(1)	I _B	4.0 8.0		Adc	
RMS Isolated Voltage(2) (for 1 sec, R.H. < 30%, T _C = 25°C)	Test No. 1 Per Fig. 22a Test No. 2 Per Fig. 22b Test No. 3 Per Fig. 22c	VISOL		4500 3500 1500	Volts
Total Device Dissipation Derate above 25°C	(T _C = 25°C)	P _D	125 1.0	45 0.36	Watts W/°C
Operating and Storage Tem	T _J , T _{stg}	– 65 t	o 150	°C	

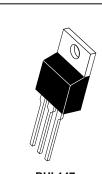
THERMAL CHARACTERISTICS

Rating	Symbol	BUL44	BUL44F	Unit
Thermal Resistance — Junction to Case — Junction to Ambient	$R_{ heta JC}$ $R_{ heta JA}$	1.0 62.5	2.78 62.5	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	TL	26	60	°C

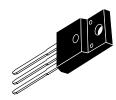
BUL147* BUL147F*

*Motorola Preferred Device

POWER TRANSISTOR 8.0 AMPERES 700 VOLTS 45 and 125 WATTS



BUL147 CASE 221A-06 TO-220AB



BUL147F CASE 221D-02 ISOLATED TO-220 TYPE UL RECOGNIZED

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector–Emitter Sustaining Voltage (I _C = 100 mA, L = 25 mH)	VCEO(sus)	400	_	_	Vdc
Collector Cutoff Current (V _{CE} = Rated V _{CEO} , I _B = 0)	I _{CEO}	_	_	100	μAdc
Collector Cutoff Current (V _{CE} = Rated V _{CES} , V _{EB} = 0)	ICES	_	_	100	μAdc
$(T_C = 125^{\circ}C)$		_	-	500	
$(V_{CE} = 500 \text{ V}, V_{EB} = 0)$ $(T_{C} = 125^{\circ}\text{C})$		_		100	
Emitter Cutoff Current (VFB = 9.0 Vdc, IC = 0)	IFBO	_	l —	100	μAdc

⁽¹⁾ Pulse Test: Pulse Width = 5.0 ms, Duty Cycle ≤ 10%.

(2) Proper strike and creepage distance must be provided.

Designer's and SWITCHMODE are trademarks of Motorola, Inc.

Designer's Data for "Worst Case" Conditions — The Designer's Data Sheet permits the design of most circuits entirely from the information presented. SOA Limit curves — representing boundaries on device characteristics — are given to facilitate "worst case" design.

Preferred devices are Motorola recommended choices for future use and best overall value.

REV 1



(continued)

	C	Characteristic			Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS	<u> </u>								
Base–Emitter Saturation Voltage (I _C = 2.0 Adc, I _B = 0.2 Adc) (I _C = 4.5 Adc, I _B = 0.9 Adc)					V _{BE(sat)}	_ _	0.82 0.92	1.1 1.25	Vdc
Collector–Emitter Saturation Voltage (I _C = 2.0 Adc, I _B = 0.2 Adc) (T _C = 125°C)				VCE(sat)	_ _	0.25 0.3 0.35	0.5 0.5 0.7	Vdc	
$(I_C = 4.5 \text{ Adc}, I_B = 0.$.9 Auc)			(T _C = 125°C)			0.35	0.7	
DC Current Gain ($I_{C} = 1.0 \text{ Adc}$, $V_{CE} = 5.0 \text{ Vdc}$) ($T_{C} = 125^{\circ}\text{C}$) ($I_{C} = 4.5 \text{ Adc}$, $V_{CE} = 1.0 \text{ Vdc}$) ($T_{C} = 125^{\circ}\text{C}$) ($T_{C} = 125^{\circ}\text{C}$) ($T_{C} = 125^{\circ}\text{C}$) ($T_{C} = 10 \text{ Mdc}$, $T_{C} = 10 \text{ Vdc}$) ($T_{C} = 10 \text{ Vdc}$) ($T_{C} = 10 \text{ Vdc}$) ($T_{C} = 10 \text{ Vdc}$)				hFE	14 — 8.0 7.0 10	— 30 12 11 18 20	34 — — — — —	_	
DYNAMIC CHARACTER						1	1		
Current Gain Bandwidt	h (lC =	0.5 Adc, V _{CE} = 10	Vdc, f =	1.0 MHz)	fΤ	_	14	_	MHz
Output Capacitance (V	CB = 1	0 Vdc, $I_E = 0$, $f = 1$.	0 MHz)		C _{ob}	_	100	175	pF
Input Capacitance (VE	3 = 8.0	V)	,		C _{ib}		1750	2500	pF
Dynamic Saturation Vol	Itage:	(I _C = 2.0 Adc I _{B1} = 200 mAdc	1.0 μs	(T _C = 125°C)		_ 	3.0 5.5	_ _	
Determined 1.0 μs ar 3.0 μs respectively a	nd after	V _{CC} = 300 V)	3.0 μs	(T _C = 125°C)	VCE(dsat)	_	0.8 1.4	_ _	Volts
rising I _{B1} reaches 90 final I _{B1})% of	$(I_{C} = 5.0 \text{ Adc})$	1.0 μs	(T _C = 125°C)	*CE(dSat)	_	3.3 8.5	_ _	Voits
(see Figure 18) I _{B1} = 0.9 Adc V _{CC} = 300 V)			3.0 μs	(T _C = 125°C)		_	0.4 1.0	_	
SWITCHING CHARACT	ERISTI	CS: Resistive Loa	d (D.C. ≤	10%, Pulse Wid	th = 20 μs)				
Turn-On Time		$(I_C = 2.0 \text{ Adc}, I_{B1} = 0.2 \text{ Adc}$ $I_{B2} = 1.0 \text{ Adc}, V_{CC} = 300 \text{ V})$ (T _C = 125°C)		(T _C = 125°C)	^t on	_ _	200 190	350 —	ns
Turn–Off Time	(T _C = 125°C)			^t off		1.0 1.6	2.5 —	μs	
Turn-On Time	$(I_{C} = 4.5 \text{ Adc}, I_{B1} = 0.9 \text{ Adc}$ $I_{B1} = 2.25 \text{ Adc}, V_{CC} = 300 \text{ V})$ $(T_{C} = 125^{\circ}\text{C})$ $(T_{C} = 125^{\circ}\text{C})$			(T _C = 125°C)	^t on	-	85 100	150 —	ns
Turn-Off Time				(T _C = 125°C)	^t off	_ _	1.5 2.0	2.5 —	μs
SWITCHING CHARACT	ERISTI	CS: Inductive Loa	d (V _{clam}	$_{p}$ = 300 V, V_{CC} =	= 15 V, L = 200 μF	1)			
Fall Time		= 2.0 Adc, I _{B1} = 0.2 = 1.0 Adc)	Adc	(T _C = 125°C)	t _{fi}	_ _	100 120	180 —	ns
Storage Time				(T _C = 125°C)	t _{Si}	_	1.3 1.9	2.5 —	μs
Crossover Time				(T _C = 125°C)	t _C	_ _	210 230	350 —	ns
Fall Time	(I _C = 4.5 Adc, I _{B1} = 0.9 Adc I _{B2} = 2.25 Adc) (T _C = 125°C)			^t fi		80 100	150 —	ns	
Storage Time				(T _C = 125°C)	t _{Si}		1.6 2.1	3.2 —	μs
Crossover Time				(T _C = 125°C)	t _C	_ _	170 200	300 —	ns
Fall Time		4.5 Adc, I _{B1} = 0.9 = 0.9 Adc)	Adc	(T _C = 125°C)	t _{fi}	60 —	— 150	180 —	ns
Storage Time				(T _C = 125°C)	t _{si}	2.6 —	— 4.3	3.8 —	μs
Crossover Time				(T _C = 125°C)	t _C	_ _	200 330	350 —	ns

TYPICAL STATIC CHARACTERISTICS

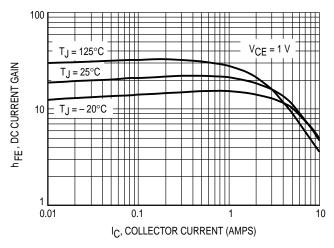


Figure 1. DC Current Gain @ 1 Volt

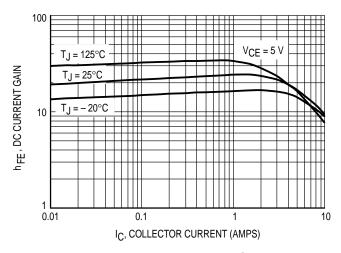


Figure 2. DC Current Gain @ 5 Volts

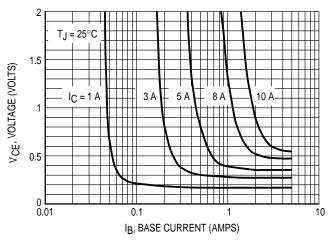


Figure 3. Collector Saturation Region

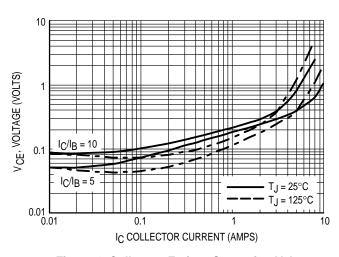


Figure 4. Collector-Emitter Saturation Voltage

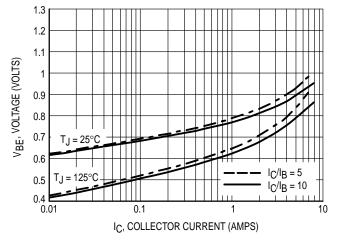


Figure 5. Base-Emitter Saturation Region

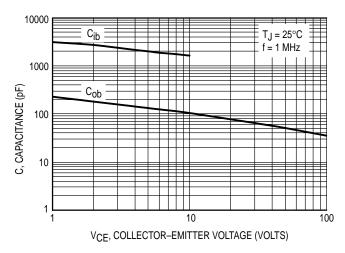


Figure 6. Capacitance

TYPICAL SWITCHING CHARACTERISTICS (IB2 = IC/2 for all switching)

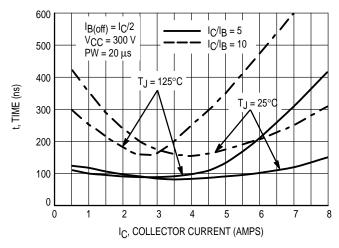


Figure 7. Resistive Switching, ton

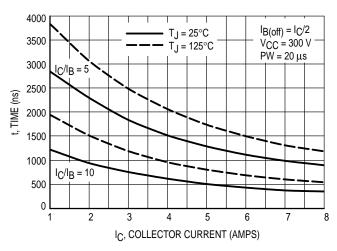


Figure 8. Resistive Switching, toff

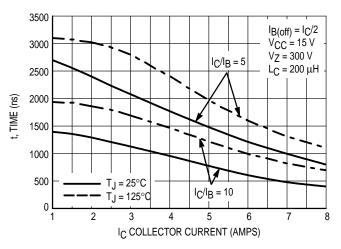


Figure 9. Inductive Storage Time, t_{Si}

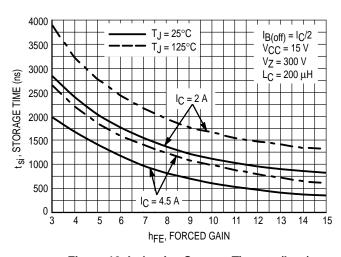


Figure 10. Inductive Storage Time, tsi(hFE)

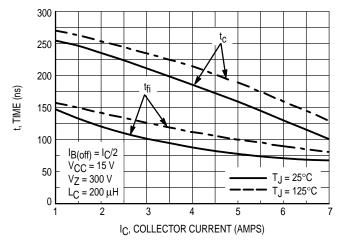


Figure 11. Inductive Switching, t_{C} and t_{fi} IC/IB = 5

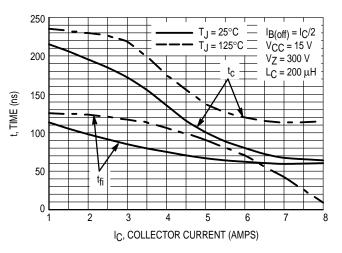
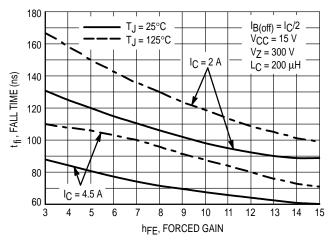


Figure 12. Inductive Switching, t_C and t_{fi} $I_C/I_B = 10$

TYPICAL SWITCHING CHARACTERISTICS (IB2 = IC/2 for all switching)

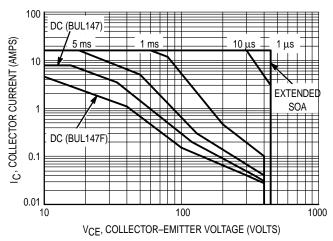


 $I_{B(off)} = I_{C}/2$ V_{CC} = 15 V 250 V_Z = 300 V T_C, CROSSOVER TIME (ns) $L_{C} = 200 \, \mu H$ 200 150 IC = 4.5 A100 $T_J = 25^{\circ}C$ T_J = 125°C 8 9 10 11 12 hFE, FORCED GAIN

Figure 13. Inductive Fall Time

Figure 14. Inductive Crossover Time

GUARANTEED SAFE OPERATING AREA INFORMATION



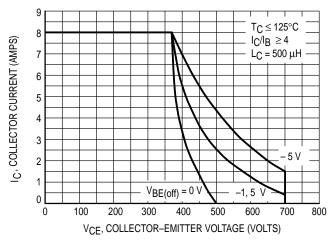


Figure 15. Forward Bias Safe Operating Area

Figure 16. Reverse Bias Switching Safe Operating Area

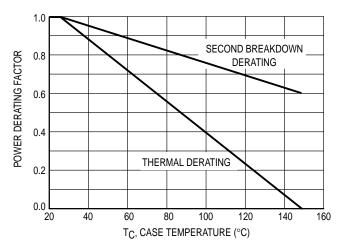
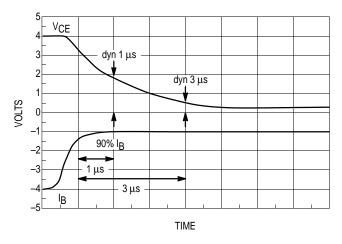


Figure 17. Forward Bias Power Derating

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate IC - VCE limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate. The data of Figure 15 is based on TC = 25°C; T_{J(pk)} is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when T_C > 25°C. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown in Figure 15 may be found at any case temperature by using the appropriate curve on Figure 17. T_{J(pk)} may be calculated from the data in Figure 20 and 21. At any case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown. For inductive loads, high voltage and current must be sustained simultaneously during turn-off with the base-to-emitter junction reverse-biased. The safe level is specified as a reverse-biased safe operating area (Figure 16). This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode.



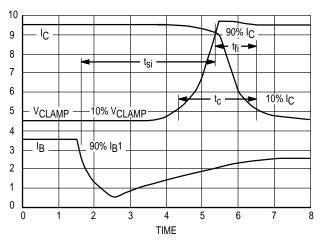


Figure 18. Dynamic Saturation Voltage Measurements

Figure 19. Inductive Switching Measurements

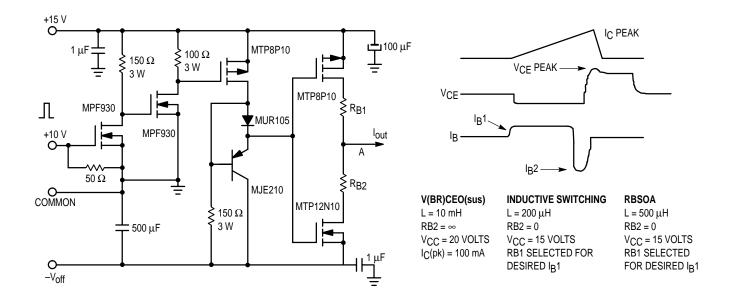


Table 1. Inductive Load Switching Drive Circuit

TYPICAL THERMAL RESPONSE

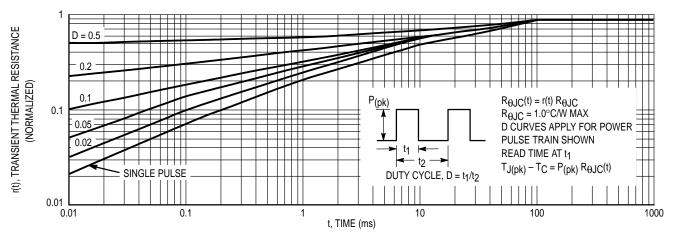


Figure 20. Typical Thermal Response ($Z_{\theta}JC(t)$) for BUL147

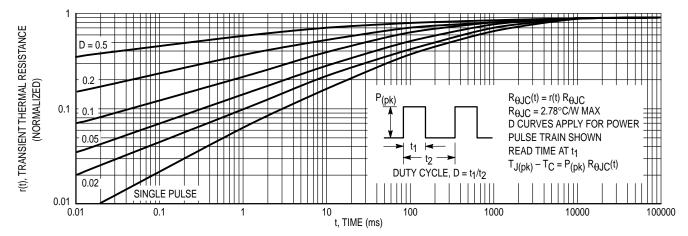
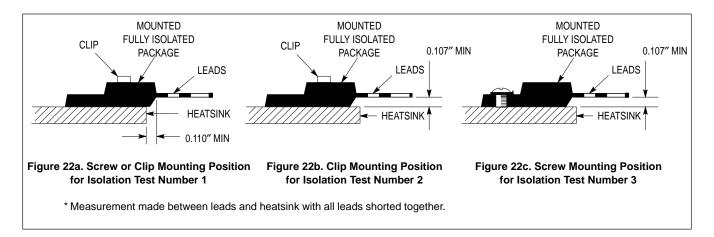


Figure 21. Typical Thermal Response ($Z_{\theta JC}(t)$) for BUL147F

TEST CONDITIONS FOR ISOLATION TESTS*



MOUNTING INFORMATION**

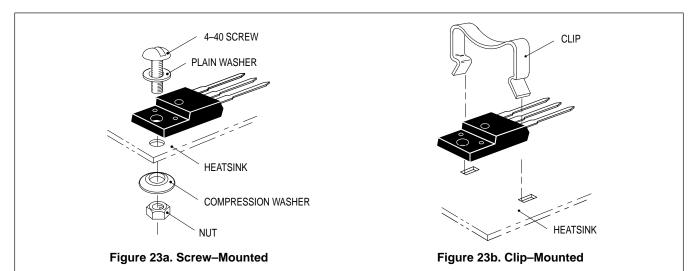


Figure 23. Typical Mounting Techniques for Isolated Package

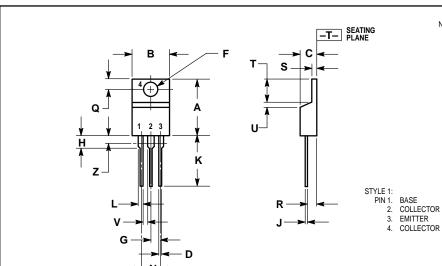
Laboratory tests on a limited number of samples indicate, when using the screw and compression washer mounting technique, a screw torque of 6 to 8 in · lbs is sufficient to provide maximum power dissipation capability. The compression washer helps to maintain a constant pressure on the package over time and during large temperature excursions.

Destructive laboratory tests show that using a hex head 4–40 screw, without washers, and applying a torque in excess of 20 in · lbs will cause the plastic to crack around the mounting hole, resulting in a loss of isolation capability.

Additional tests on slotted 4–40 screws indicate that the screw slot fails between 15 to 20 in · lbs without adversely affecting the package. However, in order to positively ensure the package integrity of the fully isolated device, Motorola does not recommend exceeding 10 in · lbs of mounting torque under any mounting conditions.

^{**} For more information about mounting power semiconductors see Application Note AN1040.

PACKAGE DIMENSIONS



NOTES:

- NOTES:

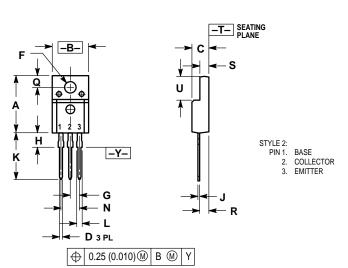
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: INCH.

 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	INCHES		IETERS			
DIM	MIN	MAX	MIN	MAX			
Α	0.570	0.620	14.48	15.75			
В	0.380	0.405	9.66	10.28			
С	0.160	0.190	4.07	4.82			
D	0.025	0.035	0.64	0.88			
F	0.142	0.147	3.61	3.73			
G	0.095	0.105	2.42	2.66			
Н	0.110	0.155	2.80	3.93			
J	0.018	0.025	0.46	0.64			
K	0.500	0.562	12.70	14.27			
L	0.045	0.060	1.15	1.52			
N	0.190	0.210	4.83	5.33			
Q	0.100	0.120	2.54	3.04			
R	0.080	0.110	2.04	2.79			
S	0.045	0.055	1.15	1.39			
Т	0.235	0.255	5.97	6.47			
U	0.000	0.050	0.00	1.27			
٧	0.045		1.15				
Z		0.080		2.04			

BUL44 **CASE 221A-06** TO-220AB **ISSUE Y**



NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.621	0.629	15.78	15.97	
В	0.394	0.402	10.01	10.21	
C	0.181	0.189	4.60	4.80	
D	0.026	0.034	0.67	0.86	
F	0.121	0.129	3.08	3.27	
G	0.100	BSC	2.54 BSC		
Н	0.123	0.129	3.13	3.27	
J	0.018	0.025	0.46	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
N	0.200	BSC	5.08 BSC		
Q	0.126	0.134	3.21	3.40	
R	0.107	0.111	2.72	2.81	
S	0.096	0.104	2.44	2.64	
C	0.259	0.267	6.58	6.78	

BUL44F CASE 221D-02 (ISOLATED TO-220 TYPE) **ISSUE D**

BUL147 BUL147F

Motorola reserves the right to make changes without further notice to any products herein. Motorola makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does Motorola assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation consequential or incidental damages. "Typical" parameters can and do vary in different applications. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. Motorola does not convey any license under its patent rights nor the rights of others. Motorola products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the Motorola product could create a situation where personal injury or death may occur. Should Buyer purchase or use Motorola products for any such unintended or unauthorized application, Buyer shall indemnify and hold Motorola and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that Motorola was negligent regarding the design or manufacture of the part. Motorola and (M) are registered trademarks of Motorola, Inc. Motorola, Inc. is an Equal Opportunity/Affirmative Action Employer.

How to reach us:

USA/EUROPE: Motorola Literature Distribution; P.O. Box 20912; Phoenix, Arizona 85036. 1–800–441–2447

MFAX: RMFAX0@email.sps.mot.com – TOUCHTONE (602) 244–6609 INTERNET: http://Design-NET.com

JAPAN: Nippon Motorola Ltd.; Tatsumi-SPD-JLDC, Toshikatsu Otsuki, 6F Seibu-Butsuryu-Center, 3-14-2 Tatsumi Koto-Ku, Tokyo 135, Japan. 03-3521-8315

HONG KONG: Motorola Semiconductors H.K. Ltd.; 8B Tai Ping Industrial Park, 51 Ting Kok Road, Tai Po, N.T., Hong Kong. 852–26629298



